

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

ADDLICATION OF	Molfmann Clauseus at al
APPLICATION OF:	Wolfgang Clemens et al.
	rrengang Cicinonic of al.

SERIAL NO: 10/517,750

GROUP ART UNIT:

Not assigned

FILED:

December 13, 2004

EXAMINER:

Not assigned

CUSTOMER NO.:

27162

FOR:

Substrate for an Organic Field Effector, Use of Said Substrate,

Method of Increasing the Charge Carrier Molility and Organic

Field Effect Transistor (OFET)

ATTY/DKT NO.:

415000-122

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria VA 22313-1450

SIR:

Pursuant to 37 C.F.R. §1.56(a), Applicant(s) hereby cite(s) the enclosed documents listed on the attached copy of Form PTO-1449 which are believed to be material to the patentability of the above-identified application.

This Information Disclosure Statement is filed in accordance with the paragraph of 37 CFR §1.97 indicated below:

X §1.97(b) This Information Disclosure Statement is filed:

- (1) Within three months of the filing date of a national application; OR
- (2) Within three months of the date of entry of the national stage of an international application; OR
- (3) Before the mailing of a first Office Action on the merits. No fee or statement is required.

____§1.97(c) This Information Disclosure Statement is filed after the period specified in paragraph (b) above, but before the mailing date of either:

- (1) A Final Action or under 37 CFR §1.113; OR
- (2) A Notice of Allowance under 37 CFR §1.311; AND

is acco	empanied by either: (check one)
	The statement as specified in 37 CFR §1.97(e) set out
	below; OR
Х	The fee of \$180.00 under 37 CFR \$1.17(p)

§1.97(d) This Information Disclosure Statement is filed after the mailing date of either: (1) a Final Action or under 37 CFR §1.113; OR A Notice of Allowance under 37 CFR §1.311; (2)

BUT filed on or before payment of the Issue Fee; AND is accompanied by:

- (1) The statement as specified in 37 CFR §1.97(e) as set forth below: AND
- Petition is hereby made under 37 CFR §1.97(d) for (2) consideration of this Information Disclosure Statement; AND.
- (3)The petition fee of \$180.00 set out in 37 CFR §1.17(i).

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	each	item	of	information	contained	in	this	Inform

ation Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing date of this Information Disclosure Statement;

or

no item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, or to the knowledge of the undersigned Attorney after making reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing date of the Information Disclosure Statement.

This Information Disclosure Statement provides a detailed list of the references cited in various pending applications listed in applicant's Disclosure Statement filed herewith.

The Commissioner is authorized to charge payment of any fees associated with this communication or credit any overpayment to Deposit Account No. 03-0678.

FIRST CLASS CERTIFICATE

I hereby certify that this correspondence is being deposited on the date set forth below with the U.S. Postal Service as First Class Mail. postage prepaid, in an envelope addressed to: **Mail Stop Amendment**

Commissioner for Patents P.O. Box 1450

Alexandria VA 22313-1450

January 5, 2005 Janice Speidel Date

#243438

Respectfully submitted. Wolfgang Clemens et al.

William Souire Reg. No. 1/25,378

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THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Organic Field Effect Transistor (OFET)

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Alexandria, VA 22313-1450

DISCLOSURE STATEMENT UNDER 37 CFR 1.56

SIR:

This paper is to bring to the attention of the PTO the following U.S. pending applications, all of which are related in different respects to organic electronic devices and/or method of making such devices such as transistors, diodes, integrated circuits and the like. Many of these applications also may have one or more common inventors.

Application No.	<u>Title</u>	Inventors	Atty. Dkt. No.
		·	
10/332,140	Method for the Production and Configuration of Organic Field-Effect Transistors (OFET)	Adolf Bernds et al.	411000-103
10/344,951	Organic Field-Effect Transistor (OFET), A Production Method Therefor, An Integrated Circuit Constructed From the Same and Their Uses	Adolf Bernds et al.	411000-99

10/362,932	Organic Field Effect Transistor, Method for Structuring an OFET and Integrated Circuit	Adolf Bemds et al	411000-110
10/380,113	Organic Rectifier, Circuit, RFID Tag and Use of an Organic Rectifier	Adolf Bemds et al.	411000-106
10/380,206	Organic Memory, Identification Marker (RFID-TAG) with Organic Memory and Uses of an Organic Memory	Adolf Bemds et al.	411000-102
10/381,032	Electrode and/or Conductor Track for Organic Components and Production Method Thereof	Adolf Bemds et al.	411000-105
10/433,959	Organic Field Effect Transistor, Method For Structuring an OFET and Integrated Circuit	Adolf Bernds	411000-108
10/433,961	Device For Detecting and/or Transmitting at Least One Environmental Influence, Method for Producing Said Device and Use Thereof	Wolfgang Clemens et al.	411000-111
10/467,636	Organic Field Effect Transistor With a Photostructured Gate Dielectric, Method for the Production and Use Thereof in Organic Electronics	Adolf Bernds et al.	411000-104
10/473,050	Device With At Least Two Organic Electronic Components and Method for Producing the Same	Adolf Bernds et al.	411000-113
10/479,234	Organic Field Effect Transistor, Method for Production and Use Thereof in the Assembly of Integrated Circuits	Adolf Bernds et al.	411000-101
10/479,238	Method For Producing Conductive Structures by Means of Printing Technique, and Active Components Produced Therefrom For Integrated Circuits	Adolf Bernds et al.	411000-100
10/492,922	Insulator for An Organic Electronic Component	Erwann Guillet et al.	411000-115
10/492,923	Electronic Unit, Circuit Design for the Same and Production Method	Wolfgang Clemens et al.	411000-114
10/498,610	Organic Field Effect Transistor with Offset Threshold Voltage and the Use Thereof	Walter Fix et al.	411000-119

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10/508,640	Logic Component Comprising Organic Field Effect Transistors	Walter Fix et al.	411000-120
10/508,737	Device and Method for Laser Structuring Functional Polymers and	Adolf Bernds et al.	411000-121
10/517,750	Substrate for an Organic Field Effect Transistor, Use of the Substrate, Method of Increasing the Charge Carrier Molility and Organic Field Effect Transistor (OFET)	Wolfgang Clemens et al.	411000-122

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Janice Speidel

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Respectfully submitted, Wolfgang Clemens et al.

William Squire Reg. No. 25,378

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Approved for use through 07/31/2006. OMB 0651-0031

Not Assigned

411000-122

U.S. Patent and Trademark Office; U.S. Department of Commerce Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number Substitute for form 1449A/PTO Complete if Known JAN 0 7 2005 **Application Number** 10/517,750 **INFORMATION DIS** Filing Date **December 13, 2004 STATEMENT** First Named Inventor Wolfgang Clemens **Group Art Unit** Not Assigned

Examiner Name

Attorney Docket Number

(Use as many sheets as necessary)

Of

11

			U.S. PATENT DOC	UMENTS	
Examiner	Cite	Document Number	Publication- Date	Name of Patentee or	Pages, Columns, Lines, Where
Initial*	No. ¹	Number-Kid Code ^{2 (if known)}	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
	1 '	US-5,574,291	11/12/1996	Dodabalapur et al.	See IDS filed 9/30/2004 on all references cited
	2	US-5,206,525	04/27/1993	Yamamoto et al.	
	3	US-6,045,977	04/04/2000	Chandross et al.	
	4	US-5,854,139	12/29/1998	Kondo et al.	,
•	5	US-5,625,199	04/29/1997	Baumbach et al.	
	6	US-5,883,397	03/16/1999	Isoda et al.	
	7	US-5,998,805	12/07/1999	Shi et al.	
	8	US-6,384,804	05/07/2002	Dodabalapur et al.	
	9	US-6,072,716	06/06/2000	Jacobsen et al.	
,	10	US-4,937,119	06/26/1990	Nickles et al.	
	11	US-5,705,826	01/06/1998	Aratani et al.	
	12	US-6,555,840	04/29/2003	Hudson et al.	1
	13	US-6,197,663	03/06/2001	Chandross et al.	

		FOREIGN	PATENT DOCU	MENTS		•
Examiner Initial*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind Code ^{5 (if known)}	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
	14	EU 0460242	12/11/1991			×
	15	WO 93 16491	08/19/1993			Х
	16	WO 99 40631	0812/1999			Х
	17	WO 99 54936	10/28/1999			Х
	18	EP 0981165	02/23/2000			Х

Examiner Signature	•	Date Considered	
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Sheet

Substitute f	te for form 1449A/PTO Complete if Known			
			Application Number	10/517,750
	INFORMATION DISCL	OSURE	Filing Date	December 13, 2004
	STATEMENT BY APPLICANT		First Named Inventor	Wolfgang Clemens
	•		Group Art Unit	Not Assigned
	(Use as many sheets as necessary)		Examiner Name	Not Assigned
Sheet	2	11	Attorney Docket Number	411000-122

			U.S. PATENT DOC	UMENTS	
Examiner	Cite	Document Number	Publication- Date	Name of Patentee or	Pages, Columns, Lines, Where
Initial*	No. ¹	Number-Kid Code ^{2 (if known)}	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear
	19	US-6,221,553	04/24/2001	Wolk et al.	
	20	US-6,150,668	11/21/2000	Bao et al.	
	21	US-6,362,509	03/26/2002	Hart	
	22	US-6,329,226	12/11/2001	Jones et al.	
	23	US-6,593,690	07/15/2003	McCormick et al.	
	24	US-6,498,114	12/24/2002	Amundson et al.	
	25	US-6,603,139	08/05/2003	Tessler et al.	
	26	US-6,621,098	09/16/2003	Jackson et al.	
	27	US-4,340,657	07/20/1982	Rowe	
	28	US-5,364,735	11/15/1994	Akamatsu et al.	
	29	US-6,330,464	12/11/2001	Colvin et al.	
	30	US-5,691,089	11/25/1997	Smayling	
	- 31	US-6,321,571	11/27/2001	Themont et al.	

		FOREIGN	PATENT DOCU	MENTS		
Examiner Initial*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind Code ^{5 (f known)}	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Τ ⁶
	32	WO 99 30432	06/17/1999			Х
	33	EP 0 108650 .	05/16/1984			Х
	34	EP 0 418504	03/27/1991			Х
	35	DE 198 51703	05/04/00			
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Examiner Signature	Date Considered	

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	INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Application Number	10/517750	
			Filing Date	December 13, 2004	
			First Named Inventor	Wolfgang Clemens	
			Group Art Unit	Not assigned	
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Initial*	No. ¹	Number-Kid Code ^{2 (if known)}	MM-DD-YYYY	Applicant of Cited Document	Relevant Passages or Relevant Figures Appear				
	37	US-6,087,196	07/11/2000	Sturm et al.	·				
	38	US-6,133,835	10/17/2000	De Leeuw et al.					
	39	US-5,970,318	10/19/1999	Choi et al.					
	40	US-5,321,240	06/14/1994	Takahira					
	41	US-5,973,598	10/26/1999	Beigel					
	42	US-5,347,144	09/13/1994	Garnier et al.					
	43	US-6,207,472	03/27/2001	Calligari et al.	_ ′ .				
•	44	US-5,486,851	01/23/1996	Gehner et al.					
	45	US-2002/0053320	05/09/2002	Duthaler					
	46	US-2004/0084670	05/06/2004	Tripsas et al.					
	47	US-							

,	FOREIGN PATENT DOCUMENTS								
Examiner Initial*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind Code ⁵ (if known)	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T⁵			
	48	EP 0 786820	07/30/1997		,	Х			
	49	WO 99 39373	08/05/1999			Х			
	50	WO 02/47183	06/13/2002			х			
	51	EP 1 103916 (title page only)	05/30/2001						
	52	EP 0 528662							
	53	EP 0 442123							

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Substitute for form 1449A/PTO			Com	plete if Known
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	INFORMATIO	N DISCLOSURE	Filing Date	December 13, 2004
,	STATEMENT	BY APPLICANT	First Named Inventor	Wolfgang Clemens
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	54	EP 0962984	12/08/99				Х
	55	WO 02 19443	03/07/02				Х
	56	WO 00 79617	12/28/04				Х
	57	WO 99 10939	03/04/99				Х
,	58	DE 100 43204	04/04/2002				
	59	EP 0 511807	11/04/1992				Х
	60	EP 0 979715	02/16/2000				
	61	EP 1 048 912	11/02/2000				
	62	DE 4243832	06/30/94				
	63	EP 0716458	06/12/1996				Х
	64	WO 99 21233	04/29/1999				Х
	65	WO 01 15233	03/01/2001				Х
Examiner S	Signature				Date Considered		

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	INFORMATION DIS	SCLOSURE	Filing Date	December 13, 2004			
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	No. ¹	Country Code ³ Number ⁴ Kind Code ^{5 (if known)}	MM-DD-YYYY	Applicant of Cited Document	Passages or Relevant Figures Appear	T ⁶
	66	WO 98/40930	09/17/98			X
	67	DE 19933757	01/25/01			
	68	FR 2793089	11/03/2000			
	69	WO 01 47045	06/28/2001			×
····	70	WO 94/17556	0804/1994			×
	71	WO 99/07189	02/11/1999			×
	72	WO 97/18944	05/29/1997			×
	73	EP 0685985	12/06/1995			×
	74	WO 00/36666	06/22/2000			X
	75	DE 100 12204 (title page)	09/20/2001			ļ
	76	DE 198 16 860	11/18/99			
	77	WO 02/065557	08/22/2002			X
Examiner				Date Considered		

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U.S. Patent and Trademark Office; U.S. Department of Commerce

Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number Substitute for form 1449A/PTO Complete if Known 10/517,750 **Application Number** INFORMATION DISCLOSURE **December 13, 2004** Filing Date STATEMENT BY APPLICANT First Named Inventor Wolfgang Clemens Not Assigned **Group Art Unit** (Use as many sheets as necessary) Not Assigned **Examiner Name** 411000-122 6 11 Attorney Docket Number Sheet

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		FOREIGN	PATENT DOCU	MENTS		
Examiner	Cite	Foreign Patent Document	Publication- Date	Name of Patentee or	Pages, Columns, Lines,	4
Initial*	No. ¹ Country Code ³ Number ⁴ Kind Code ^{5 (if known)}	MM-DD-YYYY	Applicant of Cited Document	Where Relevant Passages or Relevant Figures Appear	Τ ⁶	
	79	JP 05259434	10/05/1993			Х
	80	WO 99/10929 (title page only)	03/04/1999			X
	81	DE 199 35 527	02/08/2001			
	82	DE 199 37 262	03/01/2001			
	83	WO 01/27998 (title page only)	04/19/2001			X
	84	JP 05152560	06/18/1993			X
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Substitute f	or form 1449A/PTO		Com	plete if Known
			Application Number	10/517,750
	INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Filing Date	December 13, 2004
			First Named Inventor	Wolfgang Clemens
			Group Art Unit	Not Assigned
	(Use as many sheets as necessary)		Examiner Name	Not Assigned
Sheet	7	11	Attorney Docket Number	411000-122

NON PATENT LITERATURE DOCUMENTS

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, , ·	88	GARNIER F et al:, "Vertical Devices Architecture By Molding Of Organic-Based Thin Film Transistor", Applied Physics Letters, American Institute Of Physics. XP000784120, issn: 0003-6951 abbildung 2	x
	COLLET J. et al:, 'LOW VOLTAGE, 30 NM CHANNEL LENGTH, ORGANIC TRANSISTORS WITH A SELF-ASSEMBLED MONOLAYER AS GATE INSULATING FILMS:, APPLIED PHYSICS LETTERS, AMERICAN INSTITUTE OF PHYSICS. NEW YORK, US, Bd 76, Nr. 14, 3. april 2000 (2000-04-03), Seiten 1941-1943, XP000950589, ISSN:0003-6951, das ganze Dokument		x
	90	HWANG J D et al:, "A Vertical Submicron Slc thin film transistor", Solid State Electronics, Elsevier Science Publishers, Barking, GB, Bd. 38, NR. 2,1. February 1995 (1995-02-01), Seiten 275-278, XP004014040, ISSN:0038-1101, Abbildung 2	x
	91	ROGERS J A et al:, "Low-Voltage 0.1 Mum Organic Transistors and Complementary Inverter Circuits Fabricated with a Low-Cost Form of Near-Field Photolithography", Applied Physics Letters, American Institute of Physics. New York, US, Bd. 75, Nr. 7, 16. August 1999 (1999-08-16), Seiten 1010-1012, XP000934355, ISSN: 003-6951, das ganze Dokument	x
	92	"Short-Channel Field-Effect Transistor", IBM Technical Disclosure Bulletin, IBM Corp., New York, US, Bd. 32, Nr. 3A, 1.August 1989 (1989-08-01), Seiten 77-78, XP000049357, ISSN:0018-8689, das ganze Dokument	X
	93	REDECKER, M. et al., "Mobility enhancement through homogeneous nematic alignment of a liquid-crystalline polyfluorene", 1999 American Institute of Physics, Applied Physics Letters, Vol. 74, number 10, pp. 1400-1402.	х
-	94	ROGERS, J. A. et al:, "Printing Process Suitable for Reel-to-Reel Production of High-Performance Organic Transistors and Circuits", Advanced Materials, VCH, Verlagsgesellschaft, Weinheim, DE, Bd. 11, Nr. 9, 5. Juli 1999 (1999-07-05), Seiten 741-745, P000851834, ISSN: 0935-9648, das ganze Dokument	×
	95	MIYAMOTO, Shoichi et al:, "Effect of LDD Structure and Channel Poly-Si Thinning on a Gate-All-Around TFT (GAT) for SRAM's, IEEE Transactions on Electron Devices. Vol. 46, No. 8, August 1999	x
	96	KUMAR, Anish et al:, "Kink-Free Polycrystalline Silicon Double-Gate Elevated-Channel Thin-Film Transistors", IEEE Transactions on Electron Devices, Vol. 45, No. 12, December 1998	x
	97	CHEN, Shiao-Shien et al:, "Deep Submicrometer Double-Gate Fully-Depleted SOI PMOS Devices: A Concise Short-Channel Effect Threshold Voltage Model Using a Quasi-2D Approadh", IEEE Transaction on Electron Devices, Vol. 43, No. 9, September 1996	x

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Substitute f	or form 1449A/PTO		Com	Complete if Known	
			Application Number	10/517,750	
	INFORMATION DISC	LOSURE	Filing Date	December 13, 2004	
	STATEMENT BY APPLICANT (Use as many sheets as necessary)		First Named Inventor	Wolfgang Clemens	
			Group Art Unit	Not Assigned	
			Examiner Name	Not Assigned	
Sheet	Sheet 8 11		Attorney Docket Number	411000-122	

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	98	ZANGARA L: "Metall Statt Halbleiter, Programmierung Von Embedded ROMS Ueber Die Metallisierungen", Elektronik, Franzis Verlag GMBH, Munchen, DE, Bd. 47, Nr. 16, 4 August 1998 (1998-08-04), Seiten 52-55, XP000847917, ISSN: 0013-5658, Seite 52, rechtes Plate, Zeile 7-Seite 53, linke Spalte, Zeile 14; Abbildungen 1, 2	
	99	HERGEL, H. J.: "Pld-Programmiertechnologien", Elektronik, Franzis Verlag GMBH. Munchen, DE, Bd 41, Nr. 5, 3. Marz 1992 (1992-03-03), Seiten 44-46, XP000293121, ISSN: 0013-5658, Abbildungen 1-3.	
	100	FORREST et al.: "The Dawn of Organic Electronics", IEEE Spectrum, August 2000 (2000-08), Seiten 29-34, XP002189000, IEEE Inc., New York, US ISSN:0018-9235, Seite 33, rechte Spalte, Zelle 58-Seite 34, linke Spalte, Zeile 24; Abbildung 5.	x
	101	PATENT ABSTRACTS OF JAPAN, Vol. 009, No. 274 (E-354), 31 Oktober 1985 (1985-10-31) & JP 60 117769 A (Fujitsu KK), 25 Juni 1985 (1985-06-25) Zusammenfassung	x
	102	ZIE VOOR TITEL BOEK, de 2e PAGINA, XP-002189001, PG 196-228.	X
	103	DRURY et al., "Low-Cost All-Polymer Integrated Circuits", American Institute of Physics, Applied Physics Letters, 1998, Vol. 73, No. 1, pp 108-110, July 6, 1998.	x
	104	KUHLMANN et al., "Terabytes in Plastikfolie", Organische Massenspeicher vor der Serienproduktion	
	105	GARNIER, F. et al, "All-Polymer Field-Effect Transistor Realized by Printing Techniques", Science, American Association for the Advancement of Science, US, vol 265, 16 September 1994, pp 1684-1686.	x
	106	ASSADI A, et al:, "Field-Effect Mobility of Poly (3-Hexylthiophene) Dept. of Physics and Measurement Technology, Received 3 March 1988; accepted for Publication 17 May 1988	×

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Examiner Signature			

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INFORMATION DISCLOSURE		Filing Date	December 13, 2004	
	STATEMENT BY APPLICANT		First Named Inventor	Wolfgang Clemens
	017112		Group Art Unit	Not Assigned
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107	BAO, Z. et al., "High-Performance Plastic Transistors Fabricatecd by Printing Techniques", Chem. Mater Vol. 9, No. 6, 1997, pp 1299-1301.	x
108	HEBNER, T.R. et al., "Ink-jet printing of doped polymers for organic light emitting devices:, American Institute of Physics, Applied Physics Letters, Vol. 72, no. 5, February 2, 1998, pages 519-521.	x
109	ANGELOPOULOS M et al, "In-Situ Radiation Induced Doping", Mol. Cryst. Liq. Cryst. 1990, vol. 189, pp. 221-225.	x
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111	ROMAN et al., "POLYMER DIODES WITH HIGH RECTIFICATION:, Applied Physics Letters, Vol. 75, No. 21, November 22, 1999	x
112	PATENT ABSTRACTS OF JAPAN, Vol. 010, No. 137, May 21, 1986 (JP 361001060A)	×
113	SCHOEBEL, "Frequency Conversion with Organic-On-Inorganic Heterostructured Diodes", Extended Abstracts of the International Conference on Solid State Devices and Materials, September 1, 1997	X
114	BRAUN D., et al, "Visible light emission from semiconducting polymer diodes", American Institute of Physics, Applied Physics Letters 58, May 6, 1991, pages 1982 – 1984.	x
115	YU, G. et al., "Dual-function semiconducting polymer devices: Light-emitting and photodetecting diodes", American Institute of Physics, Applied Physics Letter 64, March 21, 1994, pages 1540 –1542.	х
116	LUCENT TECHNOLOGIES, "Innovation marks significant milestone in the development of electronic paper", Cambridge, MA and Murray Hill, NJ, November 20, 2000. XP-002209726.	x
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	No.1 107 108 109 110 111 112 113 114 115	No.¹ (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. BAO, Z. et al., "High-Performance Plastic Transistors Fabricated by Printing Techniques", Chem. Mater Vol. 9, No. 6, 1997, pp 1299-1301. HEBNER, T.R. et al., "Ink-jet printing of doped polymers for organic light emitting devices:, American Institute of Physics, Applied Physics Letters, Vol. 72, no. 5, February 2, 1998, pages 519-521. ANGELOPOULOS M et al, "In-Situ Radiation Induced Doping", Mol. Cryst. Liq. Cryst. 1990, vol. 189, pp. 221-225. DAI, L. et al, "Photochemical Generation of Conducting Pattersn in Polybutadiene Films:, Macromolecules, Vol. 29, No. 1, 1996, pages 282-287, XP 001042019, the whole document ROMAN et al., "POLYMER DIODES WITH HIGH RECTIFICATION:, Applied Physics Letters, Vol. 75, No. 21, November 22, 1999 PATENT ABSTRACTS OF JAPAN, Vol. 010, No. 137, May 21, 1986 (JP 361001060A) SCHOEBEL, "Frequency Conversion with Organic-On-Inorganic Heterostructured Diodes", Extended Abstracts of the International Conference on Solid State Devices and Materials, September 1, 1997 BRAUN D., et al, "Visible light emission from semiconducting polymer diodes", American Institute of Physics, Applied Physics Letters 58, May 6, 1991, pages 1982 – 1984. YU, G. et al., "Dual-function semiconducting polymer devices: Light-emitting and photodetecting diodes", American Institute of Physics, Applied Physics, Applied Physics Letter 64, March 21, 1994, pages 1540 –1542.

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INFORMATION	INFORMATION DISCLOSURE		September 21, 2004
STATEMENT E	STATEMENT BY APPLICANT		Wolfgang Clemens
			Not Assigned
(Use as many sheets as necessary)		Examiner Name	Not Assigned
10	11	Attorney Docket Number	411000-122

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-	118	GARNIER et al., "Conjugated Polymers and Oligomers as Active Material For Electronic Devices", Synthetic Metals, Vol. 28, 1989	X
	119	GELINCK, G.H. et al., "High-Performance All-Polymer Integrated Circuits", Applied Physics Letters, v. 77, 2000, pp. 1487-1489.	х
	120	ZHENG, Xiang-Yang et al., "Electrochemical Patterning of the Surface of Insulators with Electrically Conductive Polymers", J. Electrochem. Soc., v. 142, 1995, pp L226-L227.	x
	121	LIDZEY, D. G. et al., "Photoprocessed and Micropatterned Conjugated Polymer LEDs", Synthetic Metals, V. 82, 1996, pp. 141-148	х
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	123	ROST, Henning et al., "All-Polymer Organic Field Effect Transistors", Proc. Mat. Week, CD, 2001, pp. 1-6	x
	124	MANUELLI, Alessandro et al., "Applicability of Coating Techniques for the Production of Organic Field Effect Transistors", IEEE Polytronic 2002 Conference, 2002, pp. 201-204.	x
	125	ULLMAN, A. et al., "High Performance Organic Field-Effect Transistors and Integrated Inverters", Mat. Res. Soc. Symp. Proc., v. 665, 2001, pp. 265-270.	x
	126	FIX, W. et al., "Fast Polymer Integrated Circuits Based on a Polyfluorene Derivative", ESSDERC 2002, 2002, pp. 527-529.	x
	127	KNOBLOCH, A. et al., "Printed Polymer Transistors", Proc. Polytronic, v. 84, 2001, pp. 84-89	x
	128	FICKER, J. et al., "Dynamic and Lifetime Measurements of Polymer OFETS and Integrated Plastic Circuits, " Proc. of SPIE, v. 466, 2001, pp. 95-102	x
	129	CLEMENS, W. et al., "Vom Organischen Transistor Zum Plastik-Chip," Physik Journal, V. 2, 2003, pp. 31-36.	x

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	125	CRONE, B. ET AL, "Large-scale complementary Integrated circuits based on Organic transistors", Nature, Vol. 403, Feb. 3, 2000, PP. 521 -	х
	126	FIX, W., et al., "Fast polymer integrated circuits", American Institute of Physics, Applied Physics Letters, Vol. 81, No. 89, August 2002, pp. 1735-1737.	x
	127	DODABALAPUR, A. et al., Organic smart pixels", American Institute of Physics, Applied Physics Letters, Vol. 73, No. 2, July 13, 1998, pp. 142 – 144.	x
	128	HALLS, J.J. M., et al., "Efficient photodiodes from interpenetrating polymer networks", Nature, Vol. 376, August 10, 1995, pp. 498 – 500.	x
	129	BROWN, A.R. et al., "Field-effect transistors made from solution-processed organic semiconductors", Elsevier Science, S.A., Synthetic Metals 88 (1997) pp. 37-55	x
	130	BROWN, A.R., "Logic Gates Made from Polymer Transistors and Their Use in Ring Oscillators", Science, Vol. 270, November 10, 1995, pp 972 - 974	x
	131	KLAUK, H. et al., "Pentacene Thin Film Transistors and Inverter Circuits", 1997 International Exectron Devices Meeting Technical Digest, pages 539-542, December 1997	x
	132	KLAUK, H. et al., "Fast Organic Thin Film Transistor Circuits", IEEE Electron Device Letters, Vol. 20, no. 6, pages 289-291	x
	133	BAO, Z. et al., "Organic and Polymeric Materials for the Fabrications of Thin Film Field-Effect Transistors", paper presented at the meeting of American Chemical Society, Division of Polymer Chemistry, XX, XX, Bd. 39, Nr. 1, 29 Marz 1998 (1998-03-29), P001032497, ISSN: 0032-3934 das ganze Dokument	x
	134	PATENT ABSTRACTS OF JAPAN, vol 013, no. 444 (E-828), 5 Oktober 1989 (1989-10-05) & JP 01 169942 A (Hitachi Ltd), 5 July 1989	

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